

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- These diodes feature very low turn-on voltage and fast switching.
- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.



Case: SOD-323, Molded Plastic

• Terminals: Plated Leads Solderable per

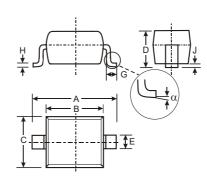
MIL-STD-202, Method 208 Polarity: Cathode Band

Weight: 0.004 grams (approx.)

Marking: L4







SOD-323					
Dim	Min	Max			
Α	2.30	2.70			
В	1.60	1.80			
С	1.20	1.40			
D	1.05 Typical				
E	0.25	0.35			
G	0.20	0.40			
Н	0.10	0.15			
J	0.05 Typical				
α	0°	8°			
All Dimensions in mm					

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	SYMBOL	VALUE	UNIT
Repetitive Peak Reverse Voltage	V _{RRM}	30	Volts
Forward Continuous Current at Tamb = 25 °C	lF	200 ¹⁾	mA
Repetitive Peak Forward Current at Tamb = 25 °C	IFRM	300 ¹⁾	mA
Surge Forward Current at tp < 1s, Tamb = 25 °C	IFSM	600 ¹⁾	mA
Power dissipation at Tamb = 25 °C	P _{tot}	150 ¹⁾	mW
Maximum Junction Temperature	Tj	150	°C
Storage Temperature Range	Ts	- 65 to +150	°C

NOTES:

(1) Valid provided that electrodes are kept at ambient temperature



Electrical Characteristics T_A = 25°C unless otherwise specified

	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse Breakdown Voltage tested with 100μA Pulses	V(BR)R	30	-	-	Volts
Forward Voltage Pulse Test tp < $300\mu s$, δ < 2% at IF = $0.1mA$ at IF = $1mA$ at IF = $10mA$ at IF = $30mA$ at IF = $100mA$	VF VF VF VF VF	- - - -	- - - -	240 320 400 500 1000	mV mV mV mV
Leakage Current Pulse Test $t_P < 300\mu s$, $\delta < 2\%$ at $V_R = 25$ V	IR	-	_	2	μΑ
Capacitance at V _F = 1 V, f = 1 MHz	Ctot	-	-	10	pF
Reverse Recovery Time from IF = 10mA through IR = 10 mA to IR = 1mA, RL = 100 Ω	t _{rr}	_	_	5	ns
Thermal Resistance Junction to Ambient Air	RthJA	_	_	650 ¹⁾	°C/W